

**ML9XX6 SERIES**

InGaAsP – MQW – FP LASER DIODES

Notice: Some parametric limits are subject to change.

**TYPE  
NAME****ML920J6S, ML920K6S  
ML925B6F, ML925C6F****DESCRIPTION**

ML9XX6 series are InGaAsP laser diodes which provide a stable, single transverse mode oscillation with emission wavelength of 1550nm and standard continuous light output of 5mW.

ML9XX6 are hermetically sealed devices having the photo diode for optical output monitoring. This is suitable for such applications as the light sources for optical communication systems.

**FEATURES**

- 1550nm typical emission wavelength, FP-LDs
  - Low threshold current, low operating current
  - Wide temperature range operation (-40 to 85°C)
  - φ5.6mm TO-CA N package
- Flat window cap : ML920J6S, ML925B6F  
Ball lens cap : ML920K6S, ML925C6F

**APPLICATION**

- Optical communication system

**ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Conditions	Ratings	Unit
Po	Light output power	CW	6[4]	mW
VRL	Laser reverse voltage	-	2	V
VRD	PD reverse voltage	-	20	V
IFD	PD forward current	-	2	mA
Tc	Operation temperature	-	-40 to +85	°C
Tstg	Storage temperature	-	-40 to +125	°C

**ELECTRICAL/OPTICAL CHARACTERISTICS(Tc=25°C)**

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Ith	Threshold current	CW	3	10	20	mA
Iop	Operation current	CW, Po=5mW[3mW]	10	30	50	mA
Vop	Operating voltage	CW, Po=5mW[3mW]	---	1.1	1.5	V
η	Slope efficiency	CW, Po=5mW[3mW]	0.15[0.1]	0.25[0.2]	---	mW/mA
λc	Center wavelength	CW, Po=5mW[3mW]	1520	1550	1580	nm
Δλ	Spectral Width	CW, Po=5mW[3mW], RMS(-20dB)	---	1.5	3	nm
θ//	Beam divergence angle(parallel)	CW, Po=5mW[3mW]	---	25[11]	---	deg.
θ⊥	Beam divergence angle (perpendicular)	CW, Po=5mW[3mW]	---	30[11]	---	deg.
tr,tf	Rise and Fall time (20%-80%)	Ib=Ith, Po=5mW[3mW], 10-90%	---	0.3	0.7	nsec
Im	Monitor Current (PD)	CW, Po=5mW[3mW], VRD=1V	0.1	0.5	1.0	mA
Id	Dark Current (PD)	VRD=10V	---	---	0.1	μA
Ct	Capacitance (PD)	VRD=10V, f=1MHz	---	10	20	pF
Pf<2>	Fiber coupled power	CW, PL=3mW, SI10/125	[0.2]	[0.5]	[--]	mW
Df<2>	Fiber coupled distance	CW, PL=3mW, SI10/125 <3>	[4.7]	[5.8]	[6.5]	mm

Note : &lt;1&gt; [ ] applied to the lens cap type.

Note : &lt;2&gt; Pf, Df are applied to the ball lens type.

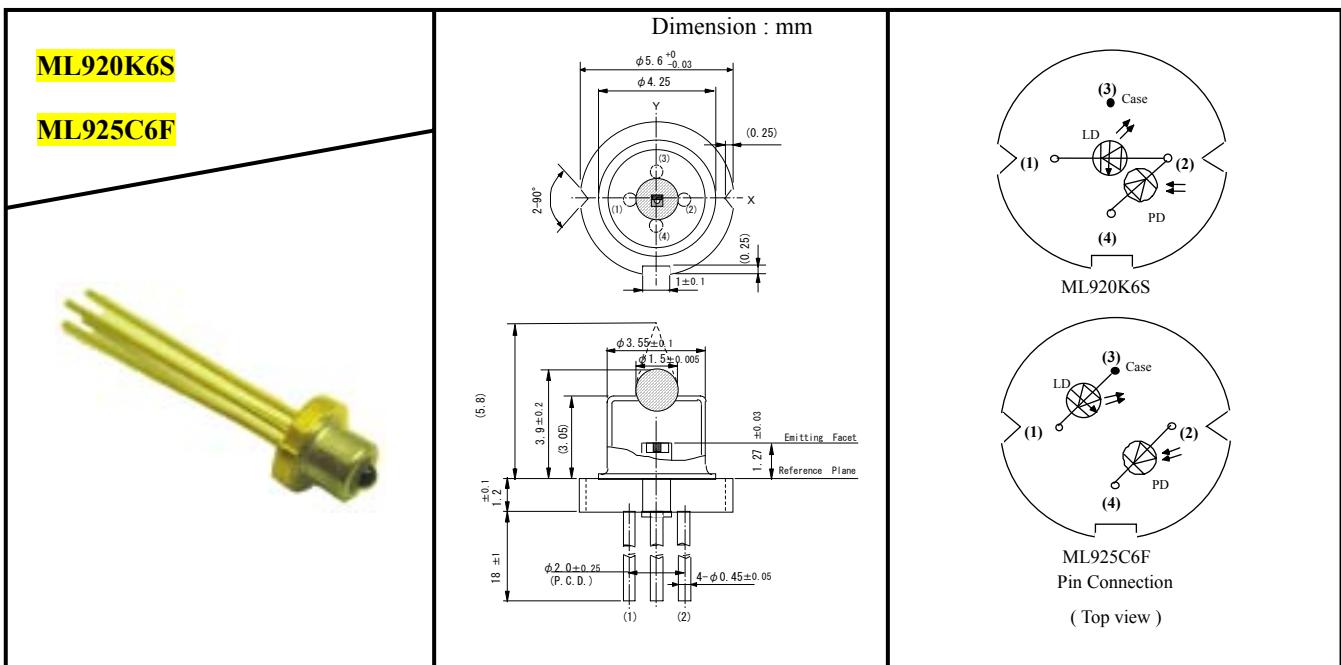
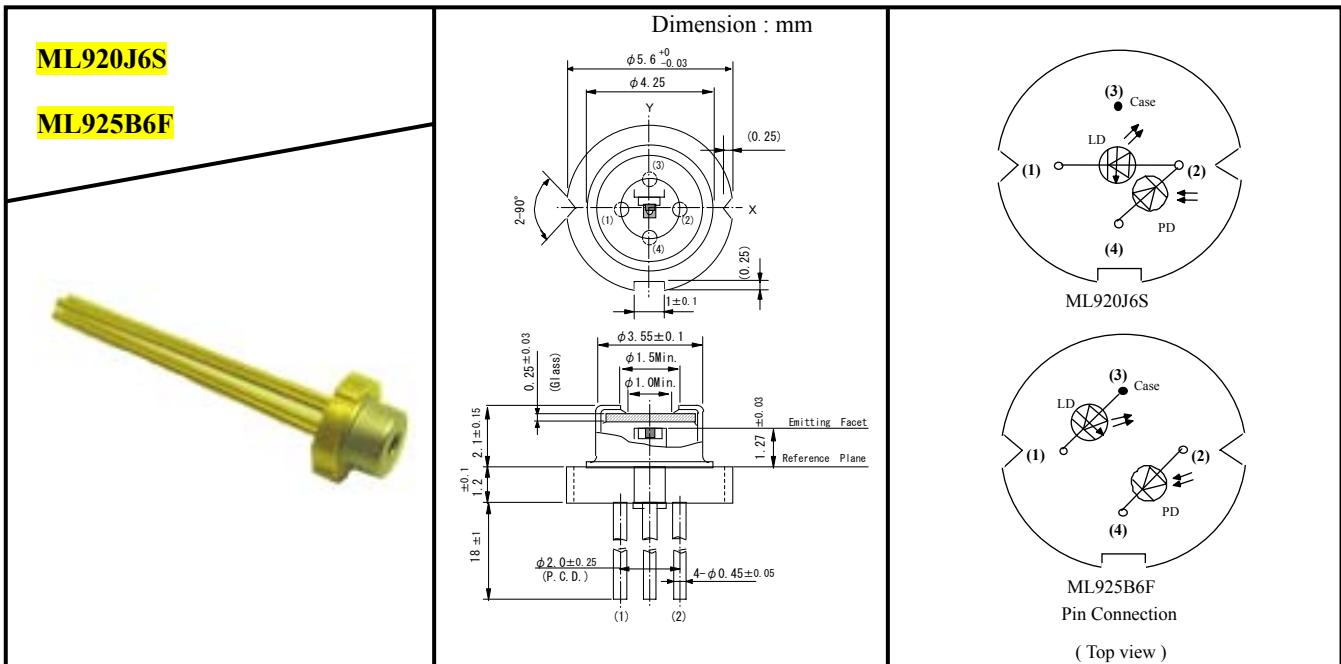
Note : &lt;3&gt; Df is a distance between reference plane of the base to the fiber.

MITSUBISHI  
ELECTRIC

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MITSUBISHI LASER DIODES  
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## **OUTLINE DRAWINGS**



**TYPICAL CHARACTERISTICS**

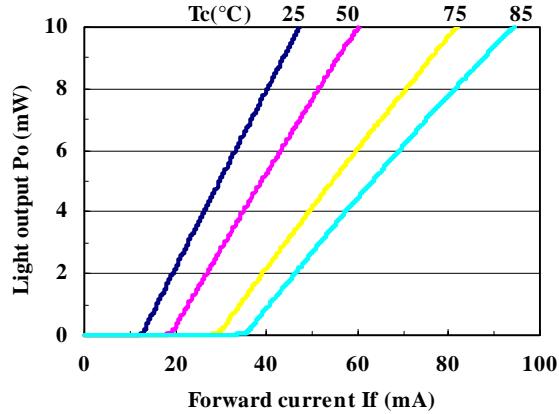


Fig.1 Light output vs. forward current

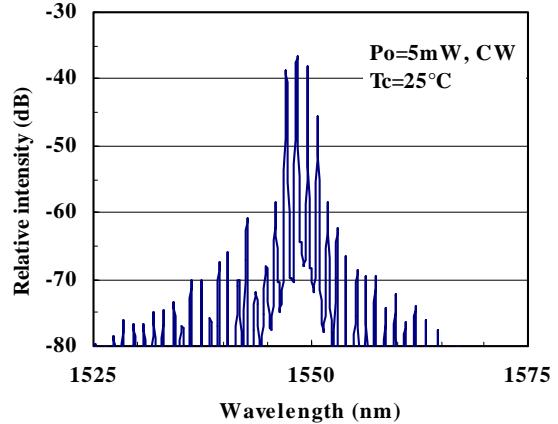


Fig.2 Spectrum

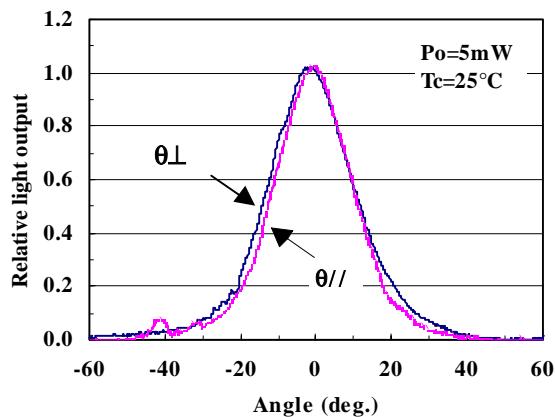


Fig.3 Far field patterns